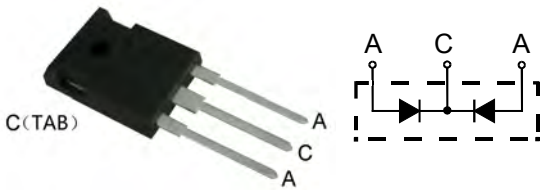


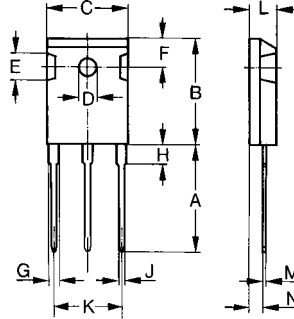
MBR3030PT thru MBR3045PT

High T_{jm} Low IRRM Schottky Barrier Diodes



A=Anode, C=Cathode, TAB=Cathode

Dimensions TO-247AD



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102

	V _{RRM}	V _{RMS}	V _{DC}
	V	V	V
MBR3030PT	30	21	30
MBR3035PT	35	24.5	35
MBR3040PT	40	28	40
MBR3045PT	45	31.5	45

Symbol	Characteristics	Maximum Ratings	Unit
I _(AV)	Maximum Average Forward Rectified Current @T _c =125°C	30	A
I _{FSM}	Peak Forward Surge Current 8.3ms Single Half-Sine-Wave Superimposed On Rated Load (JEDEC METHOD)	200	A
dv/dt	Voltage Rate Of Change (Rated V _R)	10000	V/us
V _F	Maximum Forward Voltage (Note 1)	I _F =20A @T _J =25°C I _F =20A @T _J =125°C I _F =30A @T _J =25°C I _F =30A @T _J =125°C	V
I _R	Maximum DC Reverse Current At Rated DC Blocking Voltage	@T _J =25°C @T _J =125°C	1 60 mA
R _{θJC}	Typical Thermal Resistance (Note 2)	1.4	°C/W
C _J	Typical Junction Capacitance Per Element (Note 3)	500	pF
T _J	Operating Temperature Range	-55 to +150	°C
T _{STG}	Storage Temperature Range	-55 to +175	°C

NOTES: 1. 300us Pulse Width, Duty Cycle 2%.
 2. Thermal Resistance Junction To Case.
 3. Measured At 1.0MHz And Applied Reverse Voltage Of 4.0V DC.

FEATURES

- * Metal of silicon rectifier, majority carrier conduction
- * Guard ring for transient protection
- * Low power loss, high efficiency
- * High current capability, low V_F
- * High surge capacity
- * For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- * RoHS compliant

MECHANICAL DATA

- * Case: TO-247AD molded plastic
- * Polarity: As marked on the body
- * Weight: 6 grams
- * Mounting position: Any



MBR3030PT thru MBR3045PT

High T_{jm} Low IRRM Schottky Barrier Diodes

FIG.1 - FORWARD CURRENT DERATING CURVE

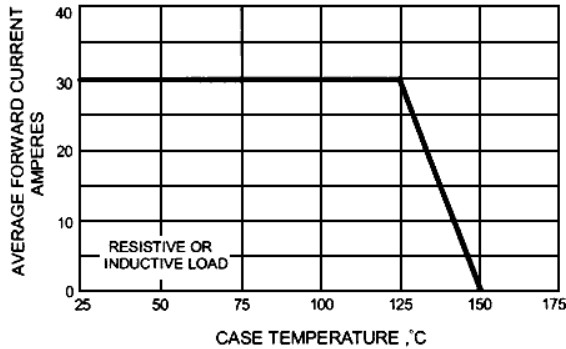


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

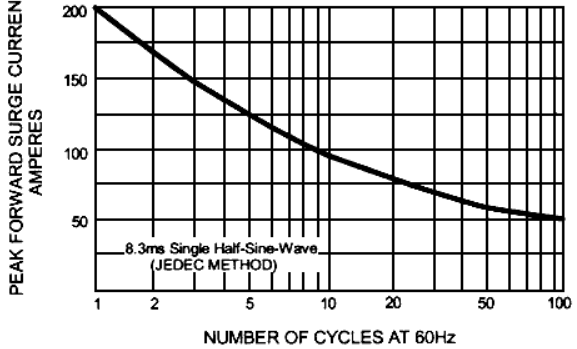


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

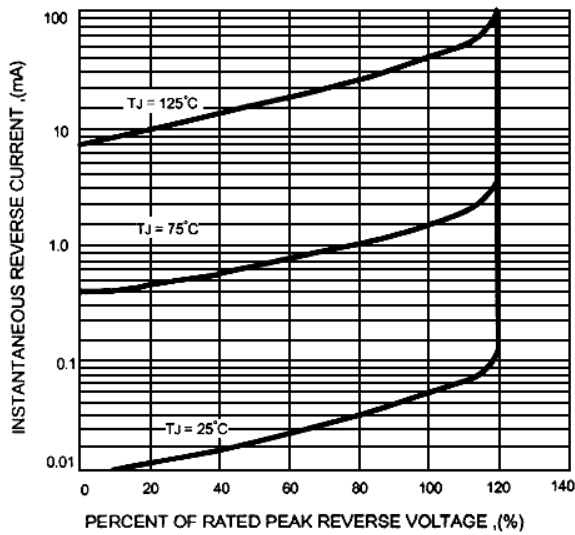


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

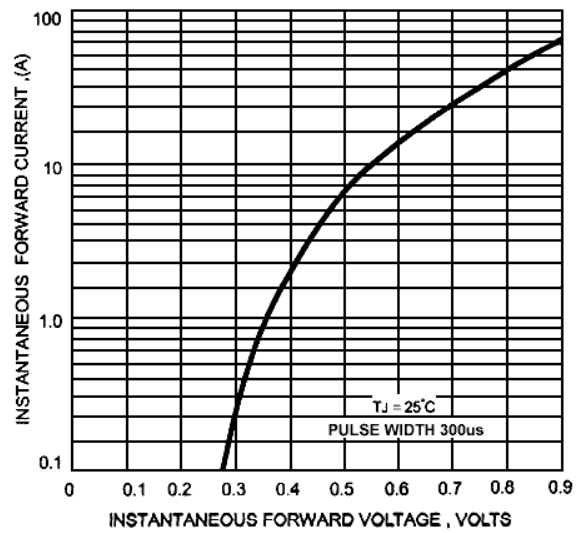


FIG.5 - TYPICAL JUNCTION CAPACITANCE

